NSN 5961-01-179-4840

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View Online at https://aerobasegroup.com/nsn/5961-01-179-4840 **Inclosure Material:** Metal **Overall Length:** 0.190 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.220 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-18 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic:

4.0 emitter to base voltage, static, collector open and 20.0 collector to base voltage/static/emitter open and 20.0 collector to emitter voltage/static/base open

Current Rating Per Characteristic:

200.00 milliamperes source cutoff current

Power Rating Per Characteristic:

1.2 watts small-signal input power, common-collector preset

Transfer Ratio:

120.0 static forward current transfer ratio, common-emitter

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: pnp

Precious Material And Location:

Lead surfaces gold

Precious Material:

Gold

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

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Demilitarization:

No

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